

Table 1. KEY SPECIFICATIONS

Description		Specification
Supply Voltages		V _{DD} = 3.3 V / 2.5 V
Frequency Range	For 2.5 V Supply For 3.3 V Supply	6 MHz < CLKIN < 12 MHz 6 MHz < CLKIN < 13 MHz
Cycle-to-Cycle Jitter		200 ps (maximum)
Output Duty Cycle		45/55% (worst case)
Modulation Rate Equation		Fin/256
Frequency Deviation		±1% @ 10 MHz

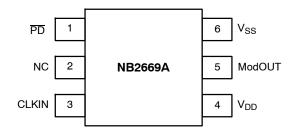


Figure 2. Pin Configuration

Table 2. PIN DESCRIPTION

Pin #	Pin Name	Туре	Description		
1	PD	I	Powerdown control pin. Pull low to enable Powerdown mode. Connect to V_{DD} if not used.		
2	NC		No connect.		
3	CLKIN	I	External reference frequency input.		
4	V _{DD}	Р	Power supply for the entire chip.		
5	ModOUT	0	Spread spectrum clock output.		
6	V _{SS}	Р	Ground connection.		

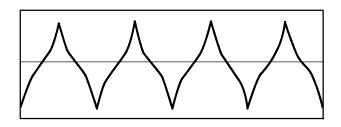


Figure 3. Modulation Profile

Table 3. MAXIMUM RATINGS

Symbol	Description	Rating	Unit
$V_{DD,}V_{IN}$	Voltage on any pin with respect to Ground	0.5 to + 7.0	V
T _{STG}	Storage Temperature	-65 to +125	°C
T _A	Operating Temperature	0 to 70	°C
T _s	Max. Soldering Temperature (10 sec)	260	°C
TJ	Junction Temperature	150	°C
T _{DV}	Static Discharge Voltage (As per MIL-STD-883, Method 3015)	2	kV

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Table 4. DC ELECTRICAL CHARACTERISTICS FOR 2.5 V SUPPLY (Test Conditions: All parameters are measured at room	
temperature 25°C)	

Symbol	Description	Min	Тур	Max	Unit
V _{IL}	Input LOW Voltage	GND - 0.3		0.8	V
V _{IH}	Input HIGH Voltage	2.0		V _{DD} + 0.3	V
IIL	Input LOW Current			-35	μA
I _{IH}	Input HIGH Current			35	μA
I _{XOL}	XOUT Output LOW Current (@ 0.5 V, V _{DD} = 2.5 V)		3.0		mA
I _{XOH}	XOUT Output HIGH Current (@ 1.8 V, V _{DD} = 2.5 V)		3.0		mA
V _{OL}	Output LOW Voltage (V _{DD} = 2.5 V, I _{OL} = 8.0 mA)			0.6	V
V _{OH}	Output HIGH Voltage (V _{DD} = 2.5 V, I _{OH} = 8.0 mA)	1.8			V
I _{DD}	Static Supply Current (Note 1)			10	μA
I _{CC}	Dynamic Supply Current (2.5 V, 10 MHz, and No Load)		2.0		mA
V _{DD}	Operating Voltage	2.375	2.5	2.625	V
t _{ON}	PLL first locked cycle time (Note 2)			5.0	mS
Z _{OUT}	Clock Output Impedance		50		Ω

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

1. XIN/CLKIN pin and PD pin are pulled low.

2. V_{DD} and CLKIN input are stable, PD pin is made high from low.

Table 5. AC ELECTRICAL CHARACTERISTICS FOR 2.5 V SUPPLY

Symbol	Description	Min	Тур	Max	Unit
CLKIN	Input Frequency	6.0		12	MHz
ModOUT	Output Frequency	6.0		12	MHz
f _d	Frequency DeviationInput Frequency = 6.0 MHzInput Frequency = 12 MHz			±1.48 ±0.79	%
t _{LH} (Note 3)	Output Rise Time (measured at 0.7 V to 1.7 V)	0.8	1.5	1.7	ns
t _{HL} (Note 3)	Output Fall Time (measured at 1.7 V to 0.7 V)	0.5	1.0	1.2	ns
t _{JC}	Jitter (Cycle-to-Cycle)			200	ps
t _D	Output Duty Cycle	45	50	55	%

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

3. t_{LH} and t_{HL} are measured at capacitive load of 15 pF.

Table 6. DC ELECTRICAL CHARACTERISTICS FOR 3.3 V SUPPLY (Test Conditions: All parameters are measured at room	n
temperature 25°C)	

Symbol	Description	Min	Тур	Max	Unit
V _{IL}	Input LOW Voltage	GND - 0.3		0.8	V
V _{IH}	Input HIGH Voltage	2.0		V _{DD} + 0.3	V
IIL	Input LOW Current			-35	μA
I _{IH}	Input HIGH Current			35	μA
I _{XOL}	XOUT Output LOW Current (@ 0.4 V, V _{DD} = 3.3 V)		3.0		mA
I _{XOH}	XOUT Output HIGH Current (@ 2.5 V, V _{DD} = 3.3 V)		3.0		mA
V _{OL}	Output LOW Voltage (V _{DD} = 3.3 V, I _{OL} = 8.0 mA)			0.4	V
V _{OH}	Output HIGH Voltage (V _{DD} = 3.3 V, I _{OH} = 8.0 mA)	2.5			V
I _{DD}	Static Supply Current (Note 4)			10	μA
I _{CC}	Dynamic Supply Current (3.3 V, 10 MHz, and No Load)		2.5		mA
V _{DD}	Operating Voltage	2.7	3.3	3.6	V
t _{ON}	PLL first locked cycle time (Note 5)			5.0	mS
Z _{OUT}	Clock Output Impedance		45		Ω

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

4. XIN/CLKIN pin and PD pin are pulled low.

5. V_{DD} and CLKIN input are stable, PD pin is made high from low.

Table 7. AC ELECTRICAL CHARACTERISTICS FOR 3.3 V SUPPLY

Symbol	Description	Min	Тур	Max	Unit
CLKIN	Input Frequency	6		13	MHz
ModOUT	Output Frequency	6		13	MHz
f _d	Frequency DeviationInput Frequency = 6.0 MHzInput Frequency = 13 MHz			±1.48 ±0.74	%
t _{LH} (Note 6)	Output Rise Time (measured at 0.8 V to 2.0 V)	0.5	1.3	1.5	ns
t _{HL} (Note 6)	Output Fall Time (measured at 2.0 V to 0.8 V)	0.4	0.9	1.1	ns
t _{JC}	Jitter (Cycle-to-Cycle)			200	ps
t _D	Output Duty Cycle	45	50	55	%

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

6. t_{LH} and t_{HL} are measured at capacitive load of 15 pF.

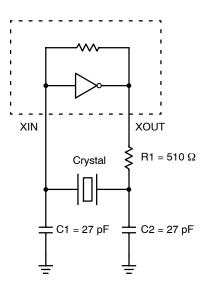


Figure 4. Typical Crystal Oscillator Circuit

Table 8. TYPICAL CRYSTAL SPECIFICATIONS

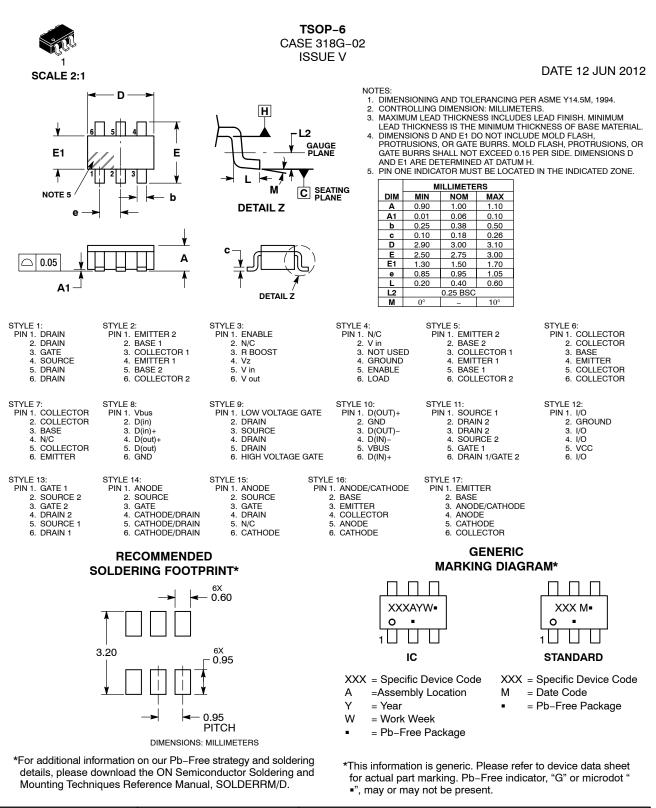
Fundamental AT Cut Parallel Resonant Crystal				
Nominal Frequency	14.31818 MHz			
Frequency Tolerance	±50 ppm or better at 25°C			
Operating Temperature Range	-25°C to +85°C			
Storage Temperature	-40°C to +85°C			
Load Capacitance	18 pF			
Shunt Capacitance	7 pF Maximum			
ESR	25 Ω			

ORDERING INFORMATION

Device	Marking	Temperature Range	Package	Shipping [†]	Availability
NB2669ASNR2	E02	0°C - 70°C	TSOP-6 (TSOT-23-6)	2500 Tape & Reel	Now
NB2669ASNR2G	E02	0°C - 70°C	TSOP-6 (TSOT-23-6) (Pb-Free)	2500 Tape & Reel	Contact Sales Representative

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.





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